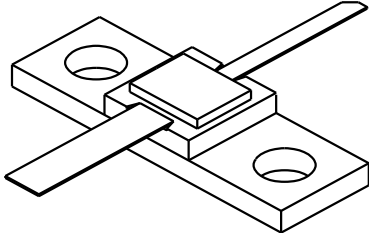


2225-4L

3.5 Watts, 24 Volts, Class C
Microwave 2200-2500 MHz

<p>GENERAL DESCRIPTION</p> <p>The 2225-4L is a COMMON BASE transistor capable of providing 3.5 Watts, Class C output power over the band 2200-2500 MHz. The transistor includes input prematching for full broadband capability. Gold metalization and diffused ballasting are used to provide high reliability and supreme ruggedness. The transistor uses a fully hermetic High Temperature Solder Sealed package.</p>	<p>CASE OUTLINE 55LV, STYLE 1</p> 
<p>ABSOLUTE MAXIMUM RATINGS</p> <p>Maximum Power Dissipation @ 25°C 10 Watts</p> <p>Maximum Voltage and Current</p> <p>BVces Collector to Emitter Voltage 40 Volts BVebo Emitter to Base Voltage 3.5 Volts Ic Collector Current 0.6 Amps</p> <p>Maximum Temperatures</p> <p>Storage Temperature - 65 to + 200°C Operating Junction Temperature + 200°C</p>	

ELECTRICAL CHARACTERISTICS @ 25 °C

SYMBOL	CHARACTERISTICS	TEST CONDITIONS	MIN	TYP	MAX	UNITS
Pout	Power Out	F = 2200-2500 MHz	3.5			Watts
Pin	Power Input	Vcc = 24 Volts			0.5	Watts
Pg	Power Gain		8.5			dB
ηc	Efficiency			40		%
VSWR	Load Mismatch Tolerance	Pout = 3.5Watts			10:1	

BVces	Collector to Emitter Breakdown	Ic = 10 mA	40			Volts
BVebo	Emitter to Base Breakdown	Ie = 5 mA	3.5			Volts
Hfe	Current Gain	Vce = 5V, Ic = 200 mA	20		120	
Cob	Output Capacitance	Vcb = 24 F = 1 MHz		7		pF
θjc	Thermal Resistance	Tc = 25°C			17.0	°C/W

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